### DTA115TM / DTA115TE / DTA115TUA / DTA115TKA / DTA115TSA

# -100mA / -50V Digital transistors (with built-in resistors) DTA115TM / DTA115TE / DTA115TUA / DTA115TKA / DTA115TSA

### Applications

Inverter, Interface, Driver

### Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on / off conditions need to be set for operation, making the device design easy.
- 4) Higher mounting densities can be achieved.

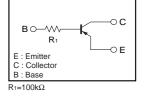
#### Structure

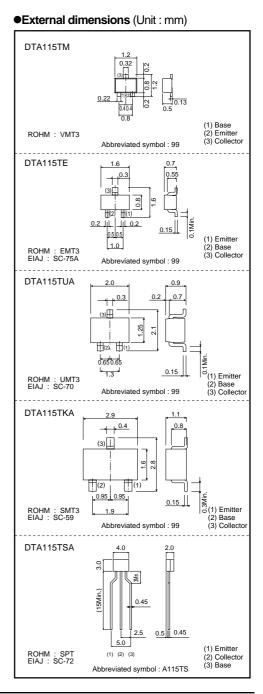
PNP epitaxial planar silicon transistor (Resistor built-in type)

### Packaging specifications

	Package	VMT3	EMT3	UMT3	SMT3	SPT
	Packaging type	Taping	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146	TP
Part No.	Basic ordering unit (pieces)	8000	3000	3000	3000	5000
DTA115	БТМ	0	_	-	-	_
DTA115	5TE	-	0	-	-	_
DTA115TUA		-	-	0	-	_
DTA115	DTA115TKA		-	-	0	-
DTA115	5TSA	-	-	-	-	

#### •Equivalent circuit





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### Transistors

### Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		Vсво	-50	V
Collector-emitter voltage		Vceo	-50	V
Emitter-base voltage		Vebo	-5	V
Collector current		lc	-100	mA
	DTA115TM / DTA115TE 15	150		
Collector power dissipation	DTA115TUA / DTA115TKA	Pc	200	mW
	DTA115TSA		300	
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

### •Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-50	-	-	V	Ic=-50μA
Collector-emitter breakdown voltage	BVCEO	-50	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВVево	-5	-	_	V	Ιε= -50μΑ
Collector cutoff current	Ісво	-	-	-0.5	μA	V <sub>CB</sub> = -50V
Emitter cutoff current	Іево	-	_	-0.5	μA	VEB=-4V
Collector-emitter saturation voltage	VCE(sat)	-	-	-0.3	V	Ic/I <sub>B</sub> =-1mA/-0.1mA
DC current transfer ratio	hfe	100	250	600	-	Ic=-1mA , Vc=-5V
Input resistance	R1	70	100	130	kΩ	-
Transition frequency	f⊤ *	_	250	-	MHz	Vce= -10V , Ie=5mA , f=100MHz

\*Characteristics of built-in transistor

### •Electrical characteristics curves

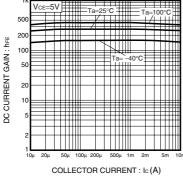


Fig.1 DC current gain vs. Collector current

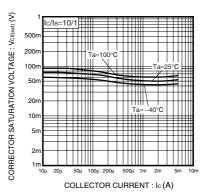


Fig.2 Collector-Emitter saturation voltage vs. Collector current

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